

1 S 397		Si-Di	=1S395: 800V	31a	=D0-26				BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 398		Si-Di	=1S395: 1000V	31a	=D0-26				BY 127, BY 133, BY 227, 1N4007, ++
1 S 399 [IR]	Inr	Si-Di	Rr, Uni, 400V, 0.8A, Uf<1,05V(0.8A)	34	D0-1				BY 126...127, BY 133...134, 1N4004...07, ++
1 S 400 [IR]		Si-Di	=1S399[IR]: 600V	34	D0-1				BY 126...127, BY 133...134, 1N4005...07, ++
1 S 401 [IR]		Si-Di	=1S399[IR]: 800V	34	D0-1				BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 401(R) [Texas]	Tix	Si-Di	=1S420(R)[Texas]						*1S420(R)[Texas]
1 S 402 [IR]		Si-Di	=1S399[IR]: 1000V	34	D0-1				BY 127, BY 133, BY 227, 1N4007, ++
1 S 402(R) [Texas]	Tix	Si-Di	=1S421(R)[Texas]						*1S421(R)[Texas]
1 S 403 [IR]		Si-Di	=1S399[IR]: 1200V	34	D0-1				BY 127, BY 133, BY 227, GP 100, ++
1 S 403(R) [Texas]	Tix	Si-Di	=1S422(R)[Texas]						*1S422(R)[Texas]
1 S 404 [IR]	Inr	Si-Di	Rr, Uni, 600V, 0.1A, Uf<6V(0.1A)	31a	(20x13mmØ)				BA 157...159, BAY 89...91, BY 203/12, ++
1 S 404(R) [Texas]	Tix	Si-Di	=1S423(R)[Texas]						*1S423(R)[Texas]
1 S 405 [IR]		Si-Di	=1S404[IR]: 800V	31a	(20x13mmØ)				BA 159, BAY 90...91, BY 203/12, ++
1 S 405(R) [Texas]	Tix	Si-Di	=1S424(R)[Texas]						*1S424(R)[Texas]
1 S 406 [IR]		Si-Di	=1S404[IR]: 1000V	31a	(20x13mmØ)				BA 159, BAY 90...91, BY 203/12, ++
1 S 406(R) [Texas]	Tix	Si-Di	=1S425(R)[Texas]						*1S425(R)[Texas]
1 S 407 [IR]		Si-Di	=1S404[IR]: 1200V	31a	(20x13mmØ)				BAY 91, BY 203/12, BY 584, SHG 1.5, ++
1 S 407(R) [Texas]	Tix	Si-Di	=1S426(R)[Texas]						*1S426(R)[Texas]
1 S 408 [IR]	Inr	Si-Di	kV-Rr, 1.5kV, 0.38A, Uf<15V(75mA)	31a	(47x15mmØ)				1N1732A
1 S 408(R) [Texas]	Tix	Si-Di	=1S427(R)[Texas]						*1S427(R)[Texas]
1 S 409 [IR]		Si-Di	=1S408[IR]: 1.8kV, 0.36A, Uf<18V(65mA)	31a	(65x15mmØ)				1N1732A
1 S 410 [IR]		Si-Di	=1S408[IR]: 2.4kV, 0.36A, Uf<12V(60mA)	31a	(65x15mmØ)				1N1733A
1 S 410 [Texas]	Tix	Si-Di	P Rr, 100V, 3A(Tc=125°), Uf<1.6V(10A)	32a	D0-4				BYX 38/300, BYX 39/600
1 S 411 [IR]		Si-Di	=1S408[IR]: 3.6kV, 0.36A, Uf<18V(65mA)	31a	(65x15mmØ)				1N1734A
1 S 411 [Texas]		Si-Di	=1S410[Texas]: 200V	32a	D0-4				BYX 38/300, BYX 39/600
1 S 412 [IR]		Si-Di	=1S408[IR]: 4.8kV, 0.36A, Uf<24V(65mA)	31a	(65x15mmØ)				1N1734A
1 S 413 [IR]		Si-Di	=1S408[IR]: 6kV, 0.36A, Uf<30V(65mA)	31a	(111x15Ø)				-
1 S 413 [Texas]		Si-Di	=1S410[Texas]: 400V	32a	D0-4				BYX 38/600, BYX 39/600
1 S 414 [IR]		Si-Di	=1S408[IR]: 7.2kV, 0.33A, Uf<36V(60mA)	31a	(111x15Ø)				-
1 S 415 [IR]		Si-Di	=1S408[IR]: 12kV, 0.25A, Uf<60V(45mA)	31a	(155x15Ø)				-
1 S 415 [Texas]		Si-Di	=1S410[Texas]: 600V	32a	D0-4				BYX 38/600, BYX 39/600
1 S 416 [IR]		Si-Di	=1S408[IR]: 16kV, 0.25A, Uf<60V(45mA)	31a	(155x15Ø)				-
1 S 417 [IR]	Inr	Si-Di	P Rr, 50V, 3A(Tc=70°), Uf<1.05V(8A)	32a	D0-4				BYX 38/300, BYX 39/600
1 S 417 [Texas]		Si-Di	=1S410[Texas]: 800V	32a	D0-4				BYX 38/900, BYX 39/800
1 S 418 [IR]		Si-Di	=1S417[IR]: 100V	32a	D0-4				BYX 38/300, BYX 39/600
1 S 419 [IR]		Si-Di	=1S417[IR]: 150V	32a	D0-4				BYX 38/300, BYX 39/600
1 S 419 [Texas]		Si-Di	=1S410[Texas]: 1000V	32a	D0-4				BYX 38/1200, BYX 39/1000
1S410R...19R [Texas]		Si-Di	=1S410...419[Texas]:	32b	D0-4				BYX 38/...R, BYX 39/...R
1 S 420 [IR]		Si-Di	=1S417[IR]: 200V	32a	D0-4				BYX 38/300, BYX 39/600
1 S 420 [Texas]	Tix	Si-Di	P Rr, 100V, 10A(Tc=100°), Uf<1.5V(30A)	32a	D0-4				BYW 88/100, BYX 76...81, 1N4506...11, ++
1 S 421 [IR]		Si-Di	=1S417[IR]: 250V	32a	D0-4				BYX 38/300, BYX 39/600
1 S 421 [Texas]		Si-Di	=1S420[Texas]: 200V	32a	D0-4				BYW 88/200, BYX 77...81, 1N4506...11, ++
1 S 422 [IR]		Si-Di	=1S417[IR]: 300V	32a	D0-4				BYX 38/300, BYX 39/600
1 S 423 [IR]		Si-Di	=1S417[IR]: 400V	32a	D0-4				BYX 38/600, BYX 39/600
1 S 423 [Texas]		Si-Di	=1S420[Texas]: 400V	32a	D0-4				BYW 88/400, BYX 78...81, 1N4507...11, ++
1 S 424 [IR]		Si-Di	=1S417[IR]: 500V	32a	D0-4				BYX 38/600, BYX 39/600
1 S 425 [IR]		Si-Di	=1S417[IR]: 600V	32a	D0-4				BYX 38/600, BYX 39/600
1 S 425 [Texas]		Si-Di	=1S420[Texas]: 600V	32a	D0-4				BYW 88/600, BYX 79...81, 1N4508...11, ++
1 S 426(G) [Japan]	Say	Ge-Di	Dem, 15...25V, 20...50mA	31a	D0-7	AA 133	31a		AA 112...114, 1N34, 1N54, 1N60, ++
1 S 427 [Japan]	Tos	Z-Di	13.5...15V, 0.3W	31a	D0-7				BZX55/C15, BZX79/C15, ZPD15, 1N5244
1 S 427 [Texas]		Si-Di	=1S420[Texas]: 800V	32a	D0-4				BYW 88/800, BYX 80...81, 1N4509...11, ++
1S420R...27R [Texas]		Si-Di	=1S420[Texas]: 800V	32b	D0-4				BYW 88/...R, BYX 86R...81R
1 S 431	Nec	Si-Di	P Rr, 100V, 100A(Tc=105°), Uf<1.6V(500A)	73a	D0-30				1N3288...97
1 S 432		Si-Di	=1S431: 200V	73a	D0-30				1N3289...97
1 S 433		Si-Di	=1S431: 300V	73a	D0-30				1N3290...97
1 S 434		Si-Di	=1S431: 400V	73a	D0-30				1N3291...97
1 S 435		Si-Di	=1S431: 500V	73a	D0-30				1N3292...97
1 S 436		Si-Di	=1S431: 600V	73a	D0-30				1N3293...97
1 S 437		Si-Di	=1S431: 700V	73a	D0-30				1N3294...97
1 S 438		Si-Di	=1S431: 800V	73a	D0-30				1N3294...97
1 S 439		Si-Di	=1S431: 900V	73a	D0-30				1N3295...97
1 S 440		Si-Di	=1S431: 1000V	73a	D0-30				1N3295...97
1 S 441	Fui	Ge-Di	Dem, Uni, 45V, 30mA	31a	D0-7				AA 113, AA 119, 1N34, 1N54, 1N60
1 S 442	Fui	Ge-Di	Dem, Uni, 43V, 0.1A	31a	D0-7	AA 133	31a		AA 113, AA 119, 1N34, 1N54, 1N60
1 S 443	Fui	Ge-Di	S, 43V, 0.12A, <2µs	31a	D0-7				AA 136, AAY 49, AAZ 15, AAZ 17
1 S 444	Fui	Ge-Di	S, 30V, 0.09A, <200ns	31a	D0-7				AAY 49, AAZ 15, AAZ 17
1 S 445	Fui	Ge-Di	S, 65V, 0.1A, <450ns	31a	D0-7				AAZ 15, AAZ 17
1 S 446	Fui	Ge-Di	Dem, Uni, 60V, 30mA	31a	D0-7	AA 133	31a		AA 113, 1N34, 1N54, 1N60
1 S 447	Fui	Ge-Di	Dem, Uni, 75V, 40mA	31a	D0-7				AA 117...118, AA 132...133
1 S 448	Fui	Ge-Di	Dem, Uni, 110V, 40mA	31a	D0-7				AA 117...118, AA 132...133
1 S 449	Fui	Ge-Di	Dem, Uni, 110V, 40mA	31a	D0-7				AA 117...118, AA 132...133
1 S 450	Fui	Ge-Di	Uni, 140V, 30mA	=2c	(15x6mmØ)				AA 133
1 S 451	Fui	Ge-Di	Dem, Uni, 60V, 40mA	31a	D0-7				AA 113, 1N43, 1N54, 1N60
1 S 452	Fui	Ge-Di	Dem, Uni, 75V, 40mA	31a	D0-7				AA 117...118, AA 132...133
1 S 453	Fui	Ge-Di	Dem, Uni, 75V, 40mA	31a	D0-7				AA 117...118, AA 132...133
1 S 454	Fui	Ge-Di	Dem, Uni, 45V, 40mA	31a	D0-7				AA 113, AA 119, 1N34, 1N54, 1N60
1 S 455	Fui	Ge-Di	Dem, Uni, 35V, 40mA	31a	D0-7				AA 113, AA 119, 1N34, 1N54, 1N60
1 S 456	Fui	Si-Di	Rr, Uni, 40V, 0.1A, Uf<1,1V(0.1A)	31a	D0-7				BA 147/50, BA 187...190, 1N5606...09, ++
1 S 457		Si-Di	=1S456: 80V	31a	D0-7				BA 147/100, BA 188...190, 1N5606...09, ++
1 S 458		Si-Di	=1S456: 150V	31a	D0-7				BA 147/150, BA 189...190, 1N5606...07, ++
1 S 459		Si-Di	=1S456: 200V	31a	D0-7				BA 147/230, BA 190, 1N5606...07, ++
1 S 460	Fui	Si-Di	SS, 22V, 0.045A, <3ns	31a	D0-7				BA 317, BAY 71, BAY 94, 1N4148...49, ++
1 S 461	Fui	Si-Di	SS, 90V, 0.15A, <3ns	31a	D0-7				BA 219, 1N4148...49, 1N4446...49, ++
1 S 462	Fui	Si-Di	SS, 90V, 0.22A, <3ns	31a	D0-7				1N4148...49, 1N4151, 1N4446...49, ++
1 S 463	Fui	Si-Di	S, 125V, 0.9A, <30ns	34	D0-1				EGP 10C, FE 1C
1 S 464	Fui, Nec	Si-St	75/225mA, Uf=0.76...0.84V(10mA), <15Ω	31a	D0-7				BA 220, BZ 102/0V7, BZX55/COV8, ZPD1
1 S 465	Fui	Si-Di	SS, 43V, 0.045A, <10ns	31a	D0-7				BA 218, BAX 13, BAX 91, 1N4148...49, ++
1 S 466	Fui	Si-Di	SS, 43V, 0.045A, <1ns	31a	D0-7				-
1 S 467	Fui, Nec	Si-St	Stabi, SS, 57/225mA, Uf=0.64...0.7V(3mA), <8c2, <6ns	31a	D0-7				BA 220, BA 315
1 S 468	Fui	Si-Di	SS, 40V, 0.115A, <3ns	31a	D0-41				BA 318, BAY 38, 1N4148...49, 1N4151, ++
1 S 470(H,L,M)	Fui	Z-Di	5.5...6.5V, 0.25W, H=+5%, L=-5%, M=±5%	31a	D0-7				BZX55/... BZX79/... ZPD... 1N5233...62, ++
1 S 471(H,L,M)		Z-Di	=1S470: 6.5...8V	31a	D0-7				
1 S 472(H,L,M)		Z-Di	=1S470: 8...10V	31a	D0-7				